

**AMENDMENTS TO THE CLAIMS:**

This listing of claims will replace all prior versions, and listings, of claims in the application:

1. (Currently amended) A transmission type liquid crystal display device comprising on a transparent substrate a gate wiring, a signal wiring perpendicular to the gate wiring, an auxiliary capacitance wiring that is generally parallel to the gate wiring and perpendicular to the signal wiring, a thin film transistor having either one of a source region and a drain region electrically connected to the signal wiring, and a pixel electrode to which the other one of the source region and the drain region of the thin film transistor is electrically connected via a lead electrode, wherein

the signal wiring, the gate wiring, the auxiliary capacitance wiring and the lead electrode are made of light shading material(s),

a semiconductor thin film is formed for a pixel electrode below and so as to be entirely covered by respective parts of the signal wiring, the gate wiring, the auxiliary capacitance wiring and the lead electrode,

a region of the semiconductor thin film located below and entirely covered by the signal wiring and below and at least partially covered by the gate wiring serves as a channel region of the thin film transistor, regions of the semiconductor thin film located

on both sides of the channel region below the signal wiring serve as a source region and a drain region of the thin film transistor respectively, and a region of the semiconductor thin film located below the auxiliary capacitance wiring serves as an auxiliary capacitance electrode region[.]; and

a first contact hole for electrically connecting either one of the source region and the drain region of the semiconductor thin film to the signal wiring, a second contact hole for electrically connecting to the lead electrode an auxiliary capacitance electrode region lead to the other one of the source region and the drain region of the semiconductor thin film, and a third contact hole for electrically connecting the lead electrode to the pixel electrode.

2. (Currently amended) A transmission type liquid crystal display device as claimed in claim 1, wherein a jut region of the semiconductor thin film in which juts from the signal wiring, the gate wiring, the auxiliary capacitance wiring and the lead electrode has an area ~~areal~~ ratio of 0.1 or less with respect to an area of an opening through which light is transmitted.

3. (Original) A transmission type liquid crystal display device as claimed in claim 1, further comprising: a lower layer light shading film formed below the semiconductor thin film and on the transparent substrate so as to cover a region that includes at least the channel region of the thin film transistor of the semiconductor thin film

4. (Original) A transmission type liquid crystal display device as claimed in claim 3, wherein the lower layer light shading film is formed on the transparent substrate so as to cover a region located between the gate wiring and the auxiliary capacitance wiring.

5. (Canceled)

6. (Previously presented) A transmission type liquid crystal display device as claimed in claim 1, wherein a gate electrode of the transistor and the auxiliary capacitance wiring are made of the same material.

7. (Original) A transmission type liquid crystal display device as claimed in claim 1, wherein the signal wiring and the lead electrode are made of a same material.

8. (Currently amended) A transmission type liquid crystal display device as claimed in claim 1, wherein the lead electrode is a thin film whose [[a]] principal component is Al, and a film layer which contains at least one substance selected from among Ir, Ru, Cr, Co, Ta, Ti, W, Mo, TiW alloy, WN, TiN and a silicide of Ir, Cr, Co, Ta, Ti, W and Mo is laminated on the lead electrode.

9-12. (Canceled)